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[Continued on next page]

(54) Title: TUNNEL FIELD EFFECT TRANSISTOR

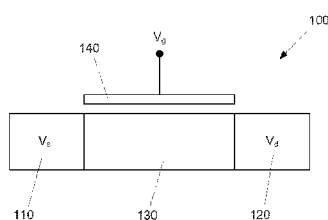


FIG. 1a (prior art)

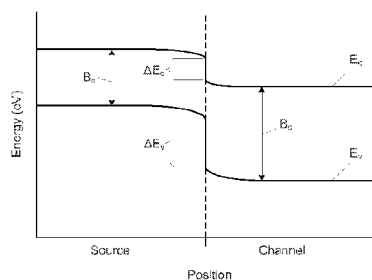


FIG. 1b (prior art)

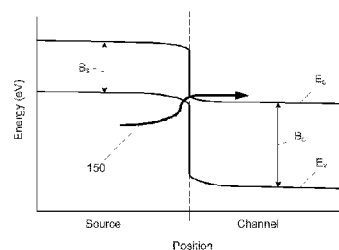


FIG. 1c (prior art)

(57) Abstract: The present disclosure relates to the field of microelectronic transistor fabrication and, more particularly, to the fabrication of a tunnel field effect transistor having an improved on-current level without a corresponding increasing the off-current level, achieved by the addition of a transition layer between a source and an intrinsic channel of the tunnel field effect transistor.





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